NSN 5961-01-231-1410

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-231-1410 **Inclosure Material:** Metal **Overall Length:** 5.000 inches **Overall Diameter:** 0.578 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 40000.0 repetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 250.00 milliamperes forward current, average **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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